NSN 5962-01-032-6848

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-032-6848 **Body Length:** Between 0.755 inches and 0.785 inches **Body Width:** Between 0.265 inches and 0.291 inches **Body Height:** Between 0.150 inches and 0.199 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** An/alq-t (v) 8459 fscm 82577 **Features Provided:** Hermetically sealed and monolithic and positive outputs and programmable and bipolar and w/buffered output and 3-state output and **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -1.0 volts power source and 5.5 volts power source **Time Rating Per Chacteristic:** 30.00 nanoseconds propagation delay time, low to high level output **Memory Device Type: Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Yes - demil/mli Fiig:

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